# 2SC5225

### Silicon NPN Epitaxial Transistor

# **HITACHI**

ADE-208-393A (Z) 2nd. Edition Mar. 2001

### **Application**

- Wide band video output amplifier for color CRT monitor.
- High frequency high voltage amplifier.
- High speed power switching.

#### **Features**

• High voltage large current operation.

$$V_{CEO} = 80 \text{ V}, I_{C} = 300 \text{ mA}$$

• High f<sub>T</sub>.

$$f_T = 1.4 \text{ GHz}$$

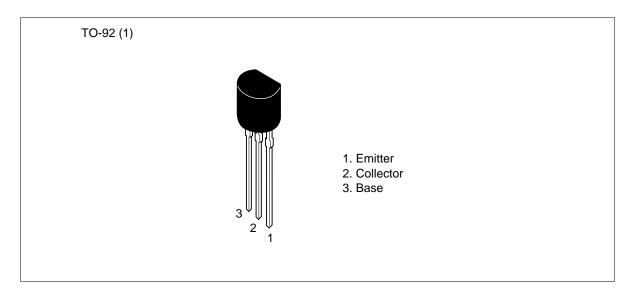
• Small output capacitance.

$$Cob = 3 pF$$



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### Outline

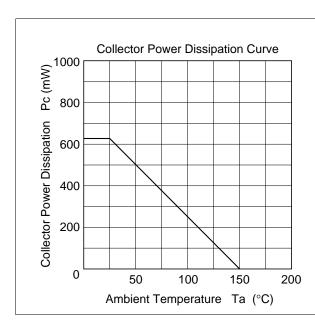


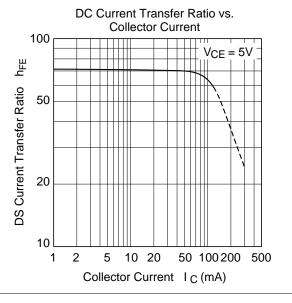
### **Absolute Maximum Ratings** ( $Ta = 25^{\circ}C$ )

Item	Symbol	Ratings	Unit ∨	
Collector to base voltage	$V_{CBO}$	100		
Collector to emitter voltage	V <sub>CEO</sub>	V <sub>CEO</sub> 80		
Emitter to base voltage	$V_{EBO}$	3	V	
Collector current	I <sub>c</sub>	300	mA	
Collector power dissipation	P <sub>c</sub>	625	mW	
Junction temperature	Tj	150	°C	
Storage temperature	Tstg	-55 to +150	°C	

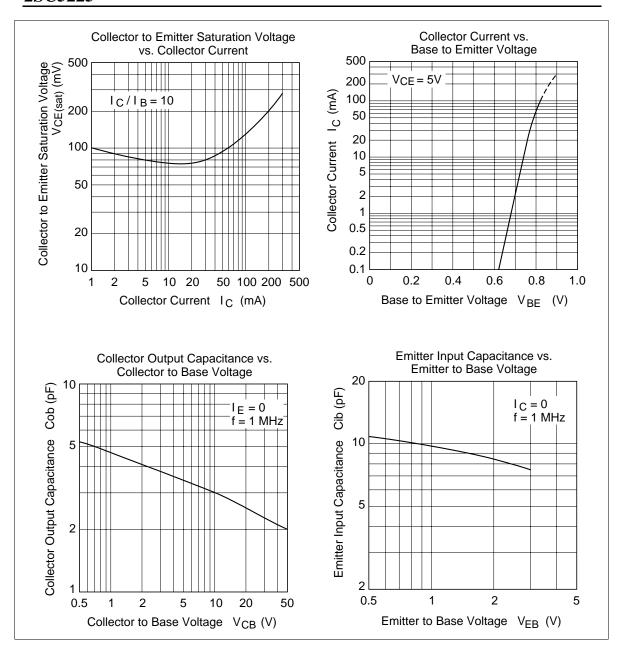
### **Electrical Characteristics** ( $Ta = 25^{\circ}C$ )

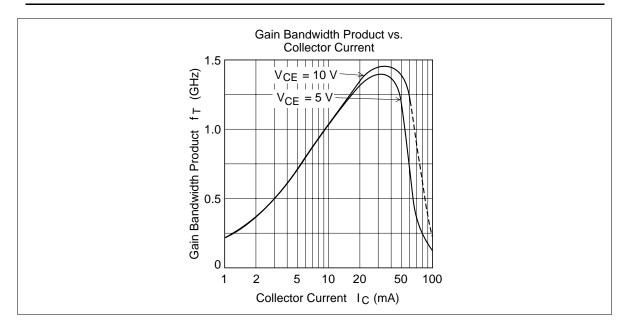
Item	Symbol	Min	Тур	Max	Unit	Test conditions
Collector to base breakdown voltage	$V_{\text{(BR)CBO}}$	100	_	_	V	$I_{c} = 100 \ \mu\text{A}, \ I_{E} = 0$
Collector to emitter breakdown voltage	$V_{(BR)CEO}$	80	_	_	V	$I_{C}$ = 1 mA, $R_{BE}$ = $\infty$
Collector to base cutoff current	I <sub>CBO</sub>	_	_	1	μΑ	$V_{CB} = 80 \text{ V}, I_{E} = 0$
Emitter to base cutoff current	I <sub>EBO</sub>	_	_	10	μΑ	$V_{EB} = 3 \text{ V}, I_{C} = 0$
DC current transfer ratio	h <sub>FE</sub>	20	70	_		$V_{CE} = 5 \text{ V}, I_{C} = 50 \text{ mA}$ Pulse test
Gain bandwidth product	f <sub>T</sub>	1.2	1.4	_	GHz	$V_{CE} = 10 \text{ V}, I_{C} = 50 \text{ mA}$
Emitter input capacitance	Cib	_	13	19	pF	$V_{EB} = 0, I_{C} = 0, f = 1 \text{ MHz}$
Collector output capacitance	Cob	_	3	4	pF	$V_{CB} = 10 \text{ V}, I_{E} = 0, f = 1 \text{ MHz}$



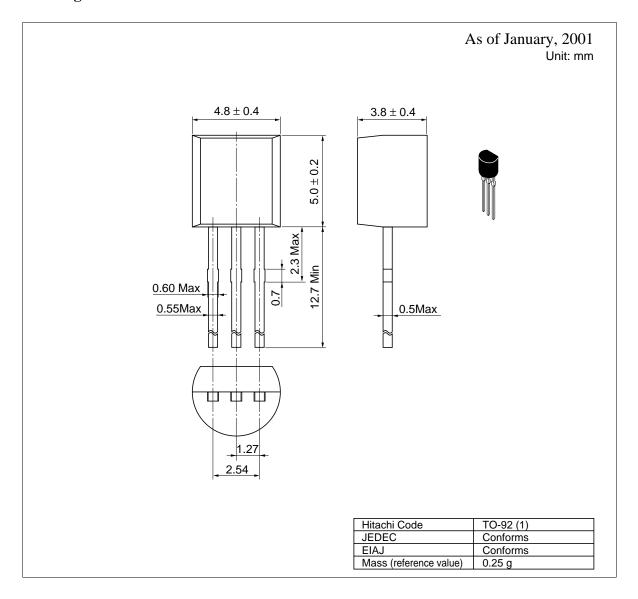


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### **Package Dimensions**



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